

ble above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}$ C unless otherwise noted.

Symbol	Parameter	Value	Unit	
V _{CEO}	Collector-Emitter Voltage	160	V	
V _{CBO}	Collector-Base Voltage	180	V	
V _{EBO}	Emitter-Base Voltage	6	V	
۱ _C	Collector Current (DC)	600	mA	
ТJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature Range	-55 to 150	°C	

Thermal Characteristics^{(1), (2)}

Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P _D	Power Dissipation ($T_C = 25^{\circ}C$)	0.7	W
	Derate Above 25°C	5.6	mW/°C
R _{θJA}	Thermal Resistance, Junction-to-Ambient	180	°C/W

Notes:

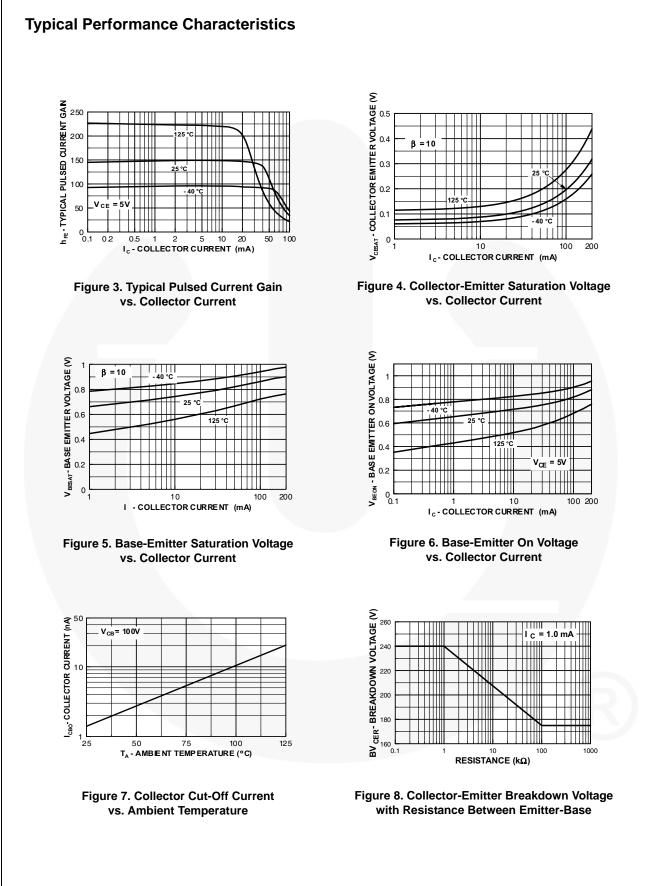
1. P_D total, for both transistors. For each transistor, P_D = 350 mW.

2. PCB size: FR-4, 76 mm x 114 mm x 1.57 mm (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

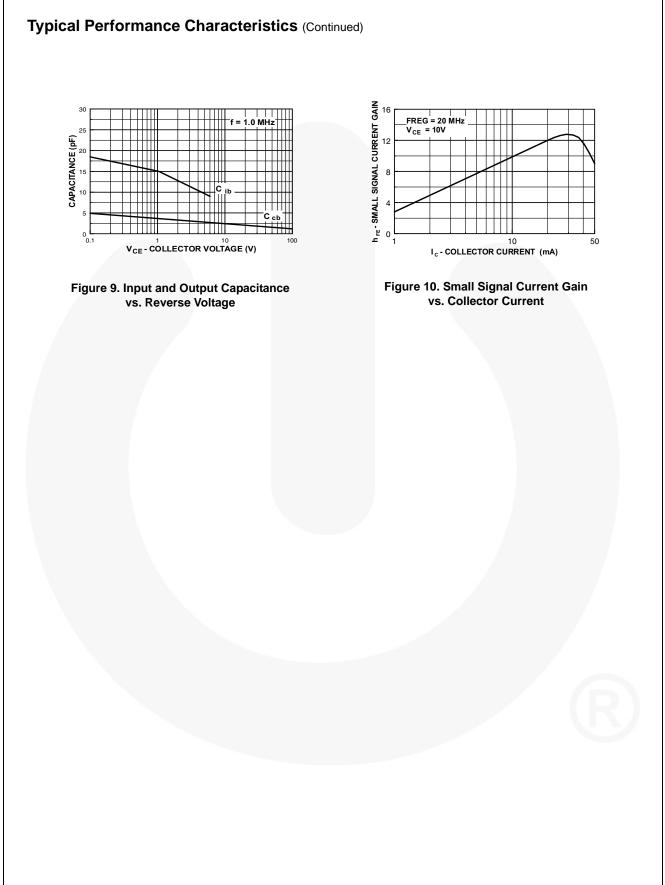
Electrical Characteristics

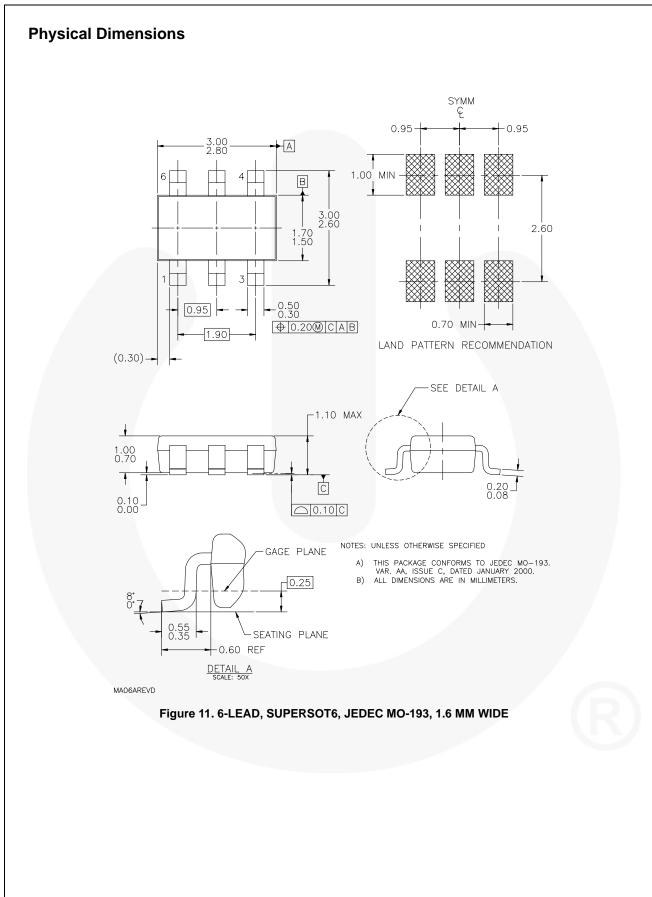
Values are at $T_A = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit	
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1 {\rm mA}, I_{\rm B} = 0$	160		V	
BV _{CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu \text{A}, \ I_{\rm E} = 0$	180		V	
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{\rm E} = 10 \ \mu {\rm A}, \ I_{\rm C} = 0$	6		V	
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0$		50	nA	
		$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0, \text{ T}_{A} = 100^{\circ}\text{C}$		50	μA	
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 4 V, I_{C} = 0$		50	nA	
h _{FE1}	DC Current Gain	$V_{CE} = 5 V, I_{C} = 1 mA$	80			
DIVID1	Variation Ratio of h _{FE1} Between Die 1 and Die 2	h _{FE1} (Die1) / h _{FE1} (Die2)	0.9	1.1		
h _{FE2}	DC Current Gain	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$	80	250		
DIVID2	Variation Ratio of h _{FE2} Between Die 1 and Die 2	h _{FE2} (Die1) / h _{FE2} (Die2)	0.95	1.05		
h _{FE3}	DC Current Gain	$V_{CE} = 5 \text{ V}, \text{ I}_{C} = 50 \text{ mA}$	30			
DIVID3	Variation Ratio of h _{FE3} Between Die 1 and Die 2	h _{FE3} (Die1) / h _{FE3} (Die2)	0.9	1.1		
V _{CE} (sat)		I _C = 10 mA, I _B = 1 mA		0.15	- v	
	Collector-Emitter Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$		0.20		
N/ (1)	Base-Emitter Saturation Voltage	$I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 1 \text{ mA}$		1	V	
V _{BE} (sat)	Base-Emilier Saturation Voltage	$I_{\rm C} = 50 \text{ mA}, I_{\rm B} = 5 \text{ mA}$		1	v	
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 5 \text{ V}, I_{C} = 10 \text{ mA}$		1	V	
DEL	Difference of V _{BE} (on) Between Die1 and Die 2	V _{BE} (on)(Die1) - V _{BE} (on)(Die2)	-8	8	mV	
C _{ob}	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		6	pF	
C _{ib}	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		20	pF	
f _T	Current Gain Bandwidth Product	$V_{CE} = 10 \text{ V}, I_{C} = 10 \text{ mA},$ f = 100 MHz	100	300	MHz	
NF	Noise Figure	$V_{CE} = 5 \text{ V}, I_C = 200 \mu\text{A},$ f = 1 MHz, R _S = 20 k Ω , B = 200 Hz		8	dB	
h _{fe}	Small Signal Current Gain	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 1.0 \text{ mA},$ f = 10 kHz	50	250		



FMBM5551 — NPN General-Purpose Amplifier





FMBM5551 — NPN General-Purpose Amplifier

FAIRCHILD. TRADEMARKS The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks. AccuPower™ F-PFS™ **OPTOPLANAR[®]** Awinda **FRFET**[®] AX-CAP®* Global Power Resource ® TinyBoost® BitSiC™ GreenBridge™ TinyBuck® PowerTrench[®] Build it Now™ Green FPS™ TinyCalc™ PowerXS™ TinyLogic® CorePLUS™ Green FPS™ e-Series™ Programmable Active Droop™ CorePOWER™ Gmax™ TINYOPTO™ QFET **CROSSVOLT™** TinyPower™ GTO™ QS™ TinyPWM™ CTI ™ IntelliMAX™ Quiet Series™ TinvWire™ Current Transfer Logic™ RapidConfigure™ **DEUXPEED**[®] TranSiC™ Making Small Speakers Sound Louder ⊃™ Dual Cool™ and Better TriFault Detect™ Saving our world, 1mW/W/kW at a time™ EcoSPARK[®] TRUECURRENT®* MegaBuck™ SignalWise™ EfficientMax™ MICROCOUPLER™ μSerDes™ SmartMax™ ESBC™ MicroFET™ SMART START™ F R MicroPak™ Solutions for Your Success™ MicroPak2™ UHC Fairchild® SPM[®] MillerDrive™ Ultra FRFET™ Fairchild Semiconductor® STEALTH™ MotionMax™ UniFET™ FACT Quiet Series™ SuperFET[®] MotionGrid® VCX™ SuperSOT™-3 **FACT[®]** FAST® MTi[®] VisualMax™ SuperSOT™-6 MTx® VoltagePlus™ FastvCore™ SuperSOT™-8 MVN® XS™ SupreMOS® FETBench™ mWSaver® Xsens™ **FPS™** SyncFET™ OptoHiT™ 仙童™ Sync-Lock™ **OPTOLOGIC®**

* Trademarks of System General Corporation, used under license by Fairchild Semiconductor.

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. TO OBTAIN THE LATEST, MOST UP-TO-DATE DATASHEET AND PRODUCT INFORMATION, VISIT OUR WEBSITE AT <u>HTTP://WWW.FAIRCHILDSEMI.COM</u>. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body or (b) support or sustain life, and (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. 172

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Fairchild Semiconductor: <u>FMBM5551</u>